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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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# Power MOSFET 30V, $50m\Omega$ , 4A, Single N-Channel

This Power MOSFET is produced using ON Semiconductor's trench technology, which is specifically designed to minimize gate charge and low on resistance. This device is suitable for applications with low gate charge driving or low on resistance requirements.

#### **Features**

- Low On-Resistance
- High Speed Switching
- 1.8V drive
- ESD Diode-Protected Gate
- Pb-Free, Halogen Free and RoHS compliance

#### **Typical Applications**

• DC/DC Converter

#### **SPECIFICATIONS**

ABSOLUTE MAXIMUM RATING at Ta = 25°C (Note 1)

Symbol	Value	Unit
VDSS	30	V
VGSS	±12	V
ID	4	Α
IDP	16	Α
PD	1	W
Tj	150	°C
Tstg	-55 to +150	°C
	VDSS VGSS ID IDP PD Tj	VDSS         30           VGSS         ±12           ID         4           IDP         16           PD         1           Tj         150

Note 1: Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### THERMAL RESISTANCE RATINGS

Parameter	Symbol	Value	Unit		
Junction to Ambient When mounted on ceramic substrate (900mm <sup>2</sup> × 0.8mm)	$R_{\theta JA}$	125	°C/W		
(900mm × 0.8mm)					

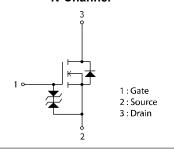


## ON Semiconductor®

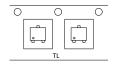
www.onsemi.com

VDSS	R <sub>DS</sub> (on) Max	ID Max
	50mΩ@ 4.5V	
30V	72mΩ@ 2.5V	4A
	130mΩ@ 1.8V	

# ELECTRICAL CONNECTION N-Channel



#### PACKING TYPE: TL MARKING





#### **ORDERING INFORMATION**

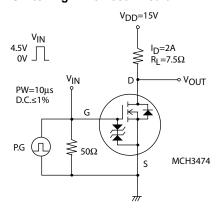
See detailed ordering and shipping information on page 5 of this data sheet.

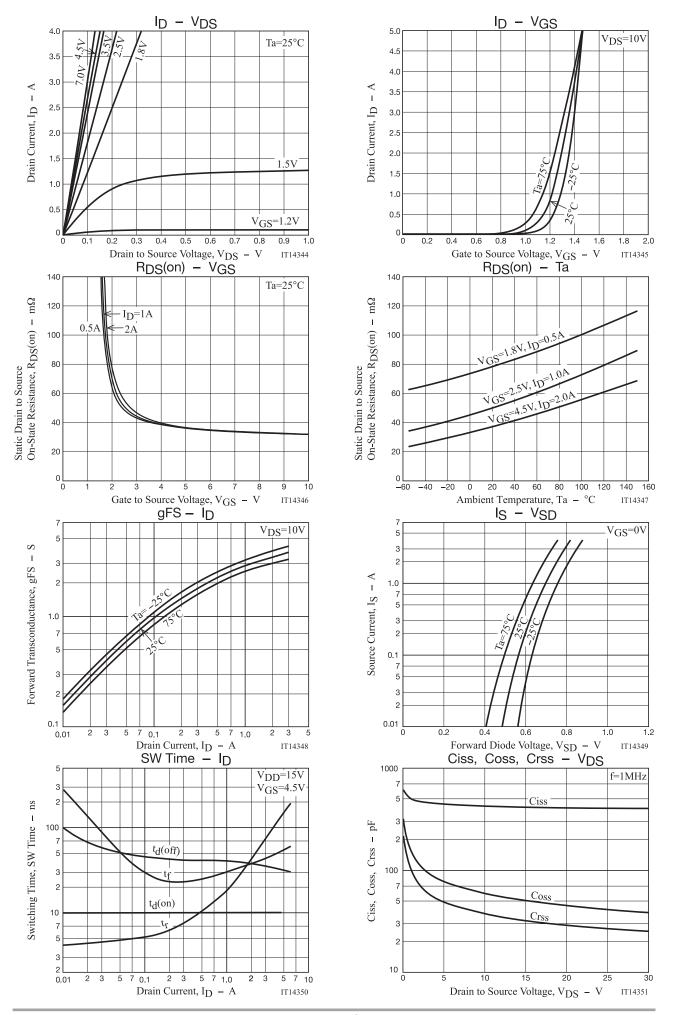
### **ELECTRICAL CHARACTERISTICS** at Ta = 25°C (Note 2)

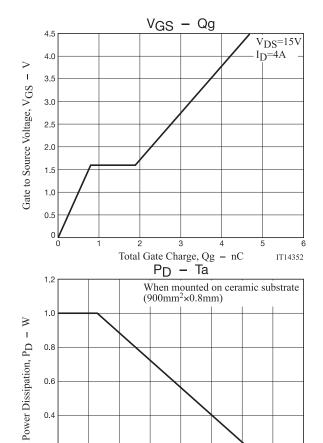
Parameter	Cumbal	Conditions	Value			Unit
Parameter	Symbol	Conditions	min	typ	max	Unit
Drain to Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	30			V
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =30V, V <sub>GS</sub> =0V			1	μΑ
Gate to Source Leakage Current	IGSS	V <sub>GS</sub> =±8V, V <sub>DS</sub> =0V			±10	μΑ
Gate Threshold Voltage	VGS(th)	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA	0.4		1.3	V
Forward Transconductance	gFS .	V <sub>DS</sub> =10V, I <sub>D</sub> =2A		3.4		S
Static Drain to Source On-State Resistance	R <sub>DS</sub> (on)1	ID=2A, VGS=4.5V		38	50	mΩ
	R <sub>DS</sub> (on)2	I <sub>D</sub> =1A, V <sub>G</sub> S=2.5V		51	72	mΩ
	RDS(on)3	ID=0.5A, VGS=1.8V		80	130	mΩ
Input Capacitance	Ciss			430		pF
Output Capacitance	Coss	V <sub>DS</sub> =10V, f=1MHz		59		pF
Reverse Transfer Capacitance	Crss			38		pF
Turn-ON Delay Time	t <sub>d</sub> (on)			10		ns
Rise Time	t <sub>r</sub>			41		ns
Turn-OFF Delay Time	t <sub>d</sub> (off)	See specified Test Circuit		36		ns
Fall Time	tf			37		ns
Total Gate Charge	Qg			4.7		nC
Gate to Source Charge	Qgs	V <sub>DS</sub> =15V, V <sub>GS</sub> =4.5V, I <sub>D</sub> =4A		0.8		nC
Gate to Drain "Miller" Charge	Qgd			1.1		nC
Forward Diode Voltage	V <sub>SD</sub>	IS=4A, VGS=0V		0.82	1.2	V

Note 2 : Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

# **Switching Time Test Circuit**



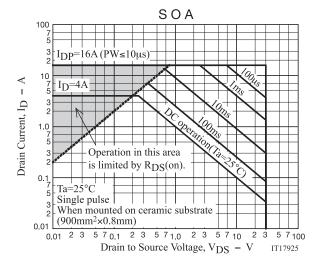


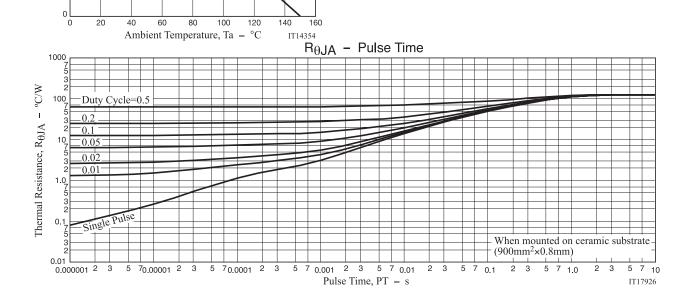


0.6

0.4

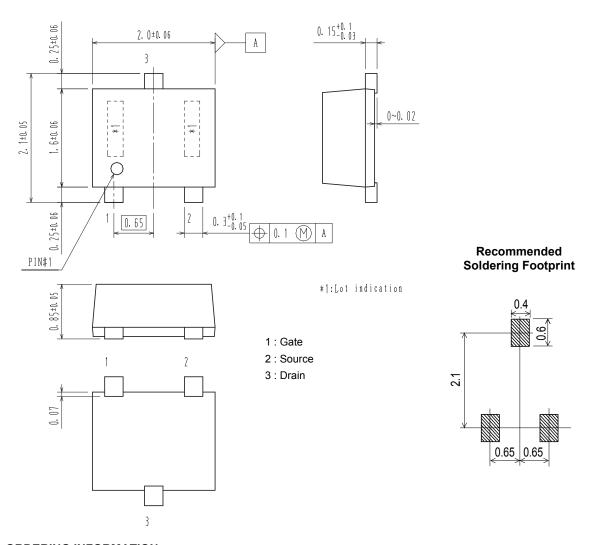
0.2





#### PACKAGE DIMENSIONS

unit: mm SC-70FL / MCPH3 CASE 419AQ ISSUE O



# ORDERING INFORMATION

Device	Marking	Package	Shipping (Qty / Packing)	
MCH3474-TL-H	FF	SC-70FL / MCPH3	2 000 / Tana & Dani	
MCH3474-TL-W	FF	(Pb-Free / Halogen Free)	3,000 / Tape & Reel	

<sup>†</sup> For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. http://www.onsemi.com/pub\_link/Collateral/BRD8011-D.PDF

Note on usage: Since the MCH3474 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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